

Silicon Carbide (SiC) Schottky Diode - EliteSiC, 8 A, 650 V, D2, T0-220-2L

FFSP0865B

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

Features

- Max Junction Temperature 175°C
- Avalanche Rated 33 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

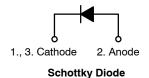
- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)s

Parameter	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage	V_{RRM}	650	V	
Single Pulse Avalanche Energy ($I_{L(pk)} = 11.5 \text{ A}, L = 0.5 \text{ mH}, V = 50$	E _{AS}	33	mJ	
Continuous Rectified Forward	@ T _C < 147	I _F	8.0	Α
Current	@ T _C < 135		10.1	
Non-Repetitive Peak Forward Surge Current	$T_C = 25^{\circ}C$ $t_P = 10 \mu s$	I _{FM}	551	Α
	T _C = 150°C t _P = 10 μs		498	
Non-Repetitive Forward Surge Current (Half-Sine Pulse)	$T_{C} = 25^{\circ}C$ $t_{P} = 8.3 \text{ ms}$	I _{FSM}	56	Α
Power Dissipation	T _C = 25°C	P _{tot}	73	W
	T _C = 150°C		12	
Operating Junction and Storage T Range	T _J , T _{stg}	-55 to +175	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

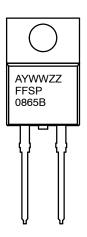
V _{RRM}	I _F
650 V	8.0 A





TO-220-2LD CASE 340BB

MARKING DIAGRAM



A = Assembly Plant Code YWW = Date Code (Year & Week) ZZ = Lot Code

FFSP0865B = Specific Device Code

ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

FFSP0865B

THERMAL CHARACTERISTICS

Parameter	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case, Max.		2.05	°C/W

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
ON CHARACTERISTICS			•			
Forward Voltage	V _F	I _F = 8.0 A, T _J = 25°C	-	1.39	1.7	V
		I _F = 8.0 A, T _J = 125°C	-	1.55	2.0	1
		I _F = 8.0 A, T _J = 175°C	-	1.71	2.4	1
Reverse Current	I _R	V _R = 650 V, T _J = 25°C	-	0.073	40	μΑ
		V _R = 650 V, T _J = 125°C	-	0.24	80	1
		V _R = 650 V, T _J = 175°C	-	0.48	160	1
CHARGES, CAPACITANCES & G	ATE RESISTANCE					
Total Capacitive Charge	Q _C	V _C = 400 V	-	22	_	nC
	C _{tot}	V _R = 1 V, f = 100 kHz	-	336	-	pF
		V _R = 200 V, f = 100 kHz	-	39	_	1
		V _R = 400 V, f = 100 kHz	-	30	-	1

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Marking	Package	Packing Method	Reel Size	Tape Width	Quantity
FFSP0865B	FFSP0865B	TO-220-2L	Tube	N/A	N/A	50 Units

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

FFSP0865B

TYPICAL CHARACTERISTICS

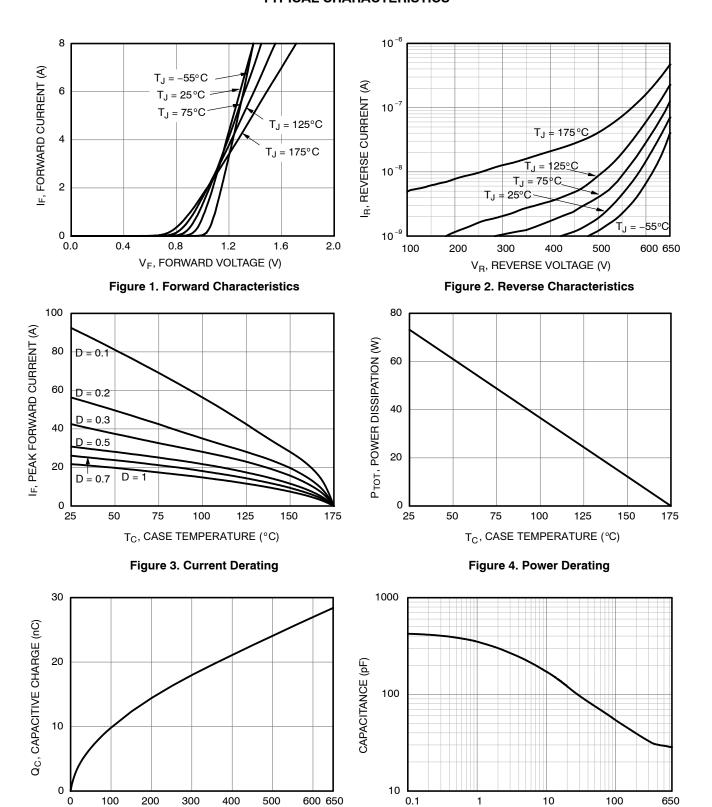


Figure 5. Capacitive Charge vs. Reverse Voltage

V_R, REVERSE VOLTAGE (V)

 $\label{eq:VR} {\sf V}_{\sf R}, \, {\sf REVERSE} \, \, {\sf VOLTAGE} \, \, ({\sf V})$ Figure 6. Capacitance vs. Reverse Voltage

FFSP0865B

TYPICAL CHARACTERISTICS

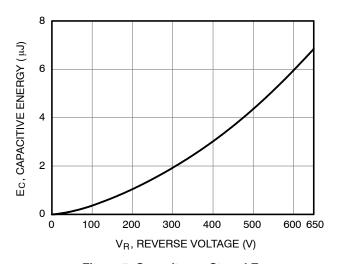


Figure 7. Capacitance Stored Energy

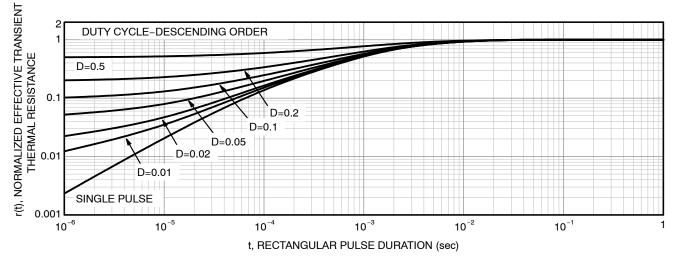
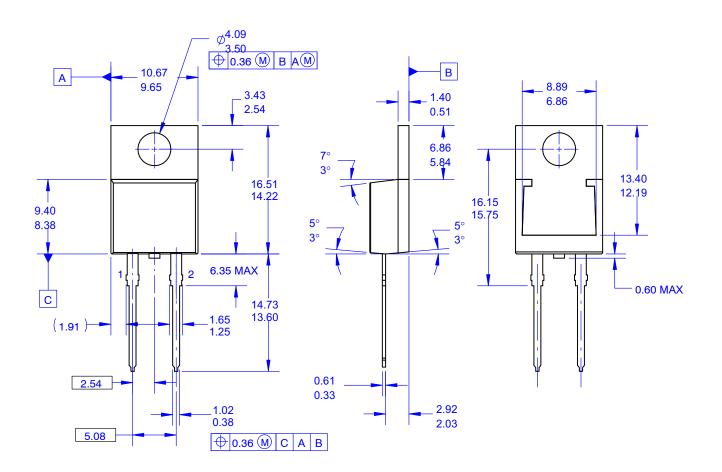


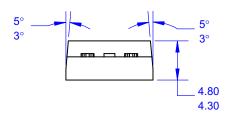
Figure 8. Junction-to-Case Transient Thermal Response



TO-220-2LD CASE 340BB ISSUE O

DATE 31 AUG 2016





NOTES:

- A. PACKAGE REFERENCE: JEDEC TO220,ISSUE K, VARIATION AC,DATED APRIL 2002.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSION AND TOLERANCE AS PER ASME Y14.5–2009.
- D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.

DOCUMENT NUMBER:	98AON13832G	Electronic versions are uncontrolled except when accessed directly from the Document Rep Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	TO-220-2LD		PAGE 1 OF 1	

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

onsemi, Onsemi, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA class 3 medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales